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List of Abbreviation and Symbols

H-H Hodgkin-Huxley

g_{Na} Sodium Conductance

g_K Potassium Conductance

g_l Leakage Conductance

V Membrane Potential

 E_{Na} Reverse potential of Sodium ions E_{K} Reverse potential of Potassium ions E_{l} Reverse potential of leakage ions

E_R Resting potential

Gating variable of activation of potassium ions
 Gating variables of activation of sodium ions
 Gating variables of inactivation of sodium ions

Ach Acetylcholine

Ache Acetylcholine esterase

AchFET Acetylcholine field effect transistor

ENFET Enzyme modified field effect transistor

ISFET Ion sensitive field effect transistor

MOSFET Metal oxide semiconductor field effect transistor

CNT Carbon nanotube
ITO Indium tin oxide

ZnO Zinc oxide

PEI Polyethylene imine
HfO₂ Hafnium dioxide
PDMS Polydimethysilxane

PBS Phosphate buffer saline

NiO Nickel oxide

CH Chitosan

AgCl Silver chloride

DMM Digital Multimeter

E-MOSFET Enhancement MOSFET

JLCNTFET Junctionless Carbon nanotube Field effect transistor

GA Genetic Algorithm

PSO Particle Swarm Optimisation

FA Firefly Algorithm

g_{ds} Conductance

V_{DS} Drain Source Voltage

 $\begin{array}{c} V_{GS} & \quad \text{Gate voltage} \\ I_{D} & \quad \text{Drain current} \end{array}$

 V_{TH} Threshold voltage